Product data sheet

1. General description

NPN/PNP low V_{CEsat} transistor pair in a SOT363 (SC-88) very small Surface-Mounted Device (SMD) plastic package. .

2. Features and benefits

- Low collector-emitter saturation voltage
- High current capability
- Replaces two SC-70 packaged low V_{CEsat} transistors on same PCB area
- Reduces required PCB area
- Reduced pick and place costs.

3. Applications

- General purpose switching and muting
- Low frequency driver circuits
- LCD backlighting
- Supply line switching circuits
- · Battery driven equipment (mobile phones, video cameras and hand-held devices).

4. Quick reference data

Table 1. Quick reference data

Symbol	Parameter	Conditions		Min	Тур	Max	Unit	
Per transistor unless otherwise specified; for the PNP transistor with negative polarity								
V _{CEO}	collector-emitter voltage	open base		-	-	15	V	
I _{CM}	peak collector current	single pulse; t _p ≤ 1 ms		-	-	1	Α	
TR1 (NPN)								
R _{CEsat}	collector-emitter saturation resistance	I_{C} = 500 mA; I_{B} = 50 mA; pulsed; t_{p} ≤ 300 µs; δ ≤ 0.02; T_{amb} = 25 °C		-	300	500	mΩ	
TR2 (PNP)	TR2 (PNP)							
R _{CEsat}	collector-emitter saturation resistance	I_C = -500 mA; I_B = -50 mA; pulsed; t_p ≤ 300 μs; δ ≤ 0.02; T_{amb} = 25 °C		-	300	500	mΩ	



5. Pinning information

Table 2. Pinning information

Pin	Symbol	Description	Simplified outline	Graphic symbol
1	E1	emitter TR1		C1 B2 E2
2	B1	base TR1	6 5 4	
3	C2	collector TR2		TR2
4	E2	emitter TR2		
5	B2	base TR2	∐1 ∐2 ∐3	I I I E1 B1 C2
6	C1	collector TR1	TSSOP6 (SOT363)	sym139

6. Ordering information

Table 3. Ordering information

Type number	Package	^a ckage				
	Name	Description	Version			
PBSS2515YPN		plastic, surface-mounted package; 6 leads; 0.65 mm pitch; 2.1 mm x 1.25 mm x 0.95 mm body	<u>SOT363</u>			

7. Marking

Table 4. Marking codes

Type number	Marking code[1]
PBSS2515YPN	N8%

^{[1] % =} placeholder for manufacturing site code

8. Limiting values

Table 5. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions		Min	Max	Unit
Per transistor	unless otherwise specified	d; for the PNP transistor with negative po	arity	'		
V _{CBO}	collector-base voltage	open emitter		-	15	V
V _{CEO}	collector-emitter voltage	open base		-	15	V
V _{EBO}	emitter-base voltage	open collector		-	6	V
I _C	collector current			-	500	mA
I _{CM}	peak collector current	single pulse; t _p ≤ 1 ms		-	1	Α
I _{BM}	peak base current			-	100	mA
P _{tot}	total power dissipation	T _{amb} ≤ 25 °C		-	200	mW
Per device			•			
P _{tot}	total power dissipation	T _{amb} ≤ 25 °C	[1]	-	300	mW
Tj	junction temperature			-	150	°C
T _{amb}	ambient temperature			-65	150	°C
T _{stg}	storage temperature			-65	150	°C

^[1] Device mounted on an FR4 PCB, single-sided copper, tin-plated and standard footprint.

9. Thermal characteristics

Table 6. Thermal characteristics

Symbol	Parameter	Conditions		Min	Тур	Max	Unit
Per transistor							
$R_{th(j-a)}$	thermal resistance from junction to ambient	in free air	[1]	-	-	416	K/W

^[1] Device mounted on an FR4 PCB, single-sided copper, tin-plated and standard footprint.

10. Characteristics

Table 7. Characteristics

Symbol	Parameter	Conditions		Min	Тур	Max	Unit
Per transis	tor unless otherwise specif	ied; for the PNP transistor with negative	e polarit	у	'	'	'
I _{CBO}	collector-base cut-off	V _{CB} = 15 V; I _E = 0 A; T _{amb} = 25 °C		-	-	100	nA
	current	V _{CB} = 15 V; I _E = 0 A; T _j = 150 °C		-	-	50	μΑ
I _{EBO}	emitter-base cut-off current	V _{EB} = 5 V; I _C = 0 A; T _{amb} = 25 °C		-	-	100	nA
TR1 (NPN)	<u> </u>						
h _{FE}	DC current gain	V _{CE} = 2 V; I _C = 10 mA; T _{amb} = 25 °C		200	-	-	
		V_{CE} = 2 V; I_{C} = 100 mA; pulsed; $t_{p} \le$ 300 μs; δ ≤ 0.02; T_{amb} = 25 °C		150	-	-	
		V_{CE} = 2 V; I_{C} = 500 mA; pulsed; $t_{p} \le$ 300 μs; δ ≤ 0.02; T_{amb} = 25 °C	1	90	-	-	
V _{CEsat}	collector-emitter saturation voltage	I_C = 10 mA; I_B = 0.5 mA; T_{amb} = 25 °C		-	-	25	mV
		I_C = 200 mA; I_B = 10 mA; T_{amb} = 25 °C		-	-	150	mV
		I_C = 500 mA; I_B = 50 mA; pulsed; $t_p \le$		-	-	250	mV
R _{CEsat}	collector-emitter saturation resistance	300 μs; δ ≤ 0.02; T _{amb} = 25 °C		-	300	500	mΩ
V _{BEsat}	base-emitter saturation voltage			-	-	1.1	V
V_{BEon}	base-emitter turn-on voltage	V_{CE} = 2 V; I_{C} = 100 mA; pulsed; $t_{p} \le$ 300 μs; δ ≤ 0.02; T_{amb} = 25 °C		-	-	0.9	V
f _T	transition frequency	V_{CE} = 5 V; I_{C} = 100 mA; f = 100 MHz; T_{amb} = 25 °C		250	420	-	MHz
C _c	collector capacitance	V_{CB} = 10 V; I_{E} = 0 A; i_{e} = 0 A; f = 1 MHz; T_{amb} = 25 °C		-	4.4	6	pF
TR2 (PNP)	<u>'</u>					,	
h _{FE}	DC current gain	V_{CE} = -2 V; I_{C} = -10 mA; T_{amb} = 25 °C		200	-	-	
		V_{CE} = -2 V; I_{C} = -100 mA; pulsed; t_{p} ≤ 300 μs; δ ≤ 0.02; T_{amb} = 25 °C		150	-	-	
		V_{CE} = -2 V; I_{C} = -500 mA; pulsed; t_{p} ≤ 300 μs; δ ≤ 0.02; T_{amb} = 25 °C		90	-	-	

15 V low VCEsat NPN/PNP transistor

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
V _{CEsat}	collector-emitter	I_C = -10 mA; I_B = -0.5 mA; T_{amb} = 25 °C	-	-	-25	mV
saturation volt	saturation voltage	I_C = -200 mA; I_B = -10 mA; T_{amb} = 25 °C	-	-	-150	mV
		$I_C = -500 \text{ mA}$; $I_B = -50 \text{ mA}$; pulsed; $t_p \le$	-	-	-250	mV
R _{CEsat}	collector-emitter saturation resistance	300 μs; δ ≤ 0.02; T _{amb} = 25 °C	-	300	500	mΩ
V _{BEsat}	base-emitter saturation voltage		-	-	-1.1	V
V_{BEon}	base-emitter turn-on voltage	V_{CE} = -2 V; I_{C} = -100 mA; pulsed; t_{p} ≤ 300 μs; δ ≤ 0.02; T_{amb} = 25 °C	-	-	-0.9	V
f _T	transition frequency	V_{CE} = -5 V; I_{C} = -100 mA; f = 100 MHz; T_{amb} = 25 °C	100	280	-	MHz
C _c	collector capacitance	V_{CB} = -10 V; I_{E} = 0 A; i_{e} = 0 A; f = 1 MHz; T_{amb} = 25 °C	-	-	10	pF

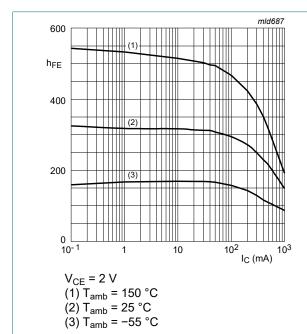
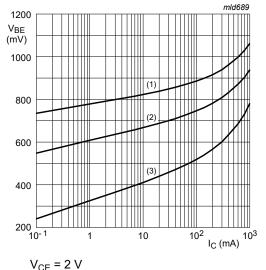
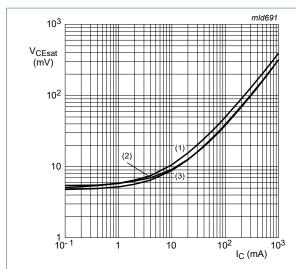


Fig. 1. TR1 (NPN): DC current gain as a function of collector current; typical values



 $V_{CE} = 2 V$ (1) $T_{amb} = -55 °C$ (2) $T_{amb} = 25 °C$ (3) $T_{amb} = 150 °C$

Fig. 2. TR1 (NPN): Base-emitter voltage as a function of collector current; typical values

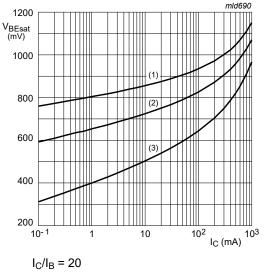


 $I_{\rm C}/I_{\rm B} = 20$

(1) $T_{amb} = 150 \, ^{\circ}C$

(2) $T_{amb} = 25 \text{ °C}$ (3) $T_{amb} = -55 \text{ °C}$

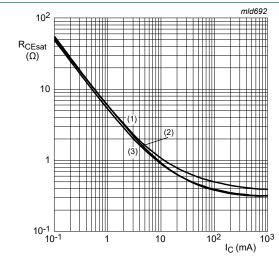
TR1 (NPN): Collector-emitter saturation voltage Fig. 3. as a function of collector current; typical values



(1) $T_{amb} = 150 \, ^{\circ}C$

(2) $T_{amb} = 25 \text{ °C}$ (3) $T_{amb} = -55 \text{ °C}$

TR1 (NPN): Base-emitter saturation voltage as a Fig. 4. function of collector current; typical values



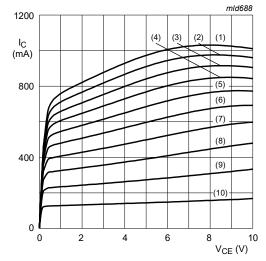
 $I_C/I_B = 20$

(1) $T_{amb} = 150 \, ^{\circ}C$

(2) T_{amb} = 25 °C

 $(3) T_{amb} = -55 °C$

Fig. 5. TR1 (NPN): Equivalent on-resistance as a function of collector current; typical values



 T_{amb} = 25 °C

(1) $I_B = 4.6 \text{ mA}$

(2) $I_B = 4.14 \text{ mA}$

(3) $I_B = 3.68 \text{ mA}$

 $(4) I_B = 3.22 \text{ mA}$

(5) $I_B = 2.76 \text{ mA}$ (6) $I_B = 2.3 \text{ mA}$

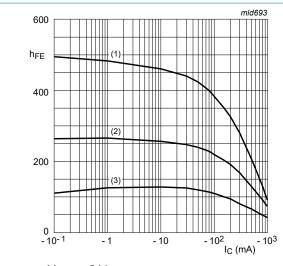
 $(7) I_B = 1.84 \text{ mA}$

(8) $I_B = 1.38 \text{ mA}$

(9) $I_B = 0.92 \text{ mA}$

 $(10) I_B = 0.46 \text{ mA}$

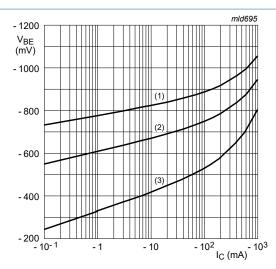
Fig. 6. TR1 (NPN): Collector current as a function of collector-emitter voltage; typical values



$$V_{CE} = -2 V$$

$$(1) T_{amb} = 150 °($$

Fig. 7. TR2 (PNP): DC current gain as a function of collector current; typical values

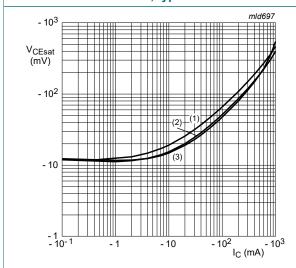


$$V_{CE} = -2 V$$

(2)
$$T_{amb} = 25 \, ^{\circ}C$$

(3)
$$T_{amb} = 150 \, ^{\circ}C$$

Fig. 8. TR2 (PNP): Base-emitter voltage as a function of collector current; typical values



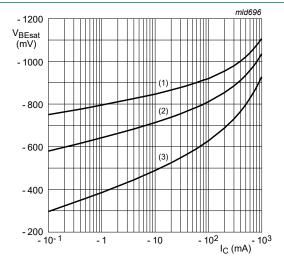
$$I_C/I_B = 20$$

(1)
$$T_{amb}$$
 = 150 °C

$$(2) T_{amb} = 25 °C$$

(3)
$$T_{amb} = -55 \,^{\circ}C$$

Fig. 9. TR2 (PNP): Collector-emitter saturation voltage as a function of collector current; typical values



$$I_{\rm C}/I_{\rm B}=20$$

(1)
$$T_{amb} = 150 \, ^{\circ}C$$

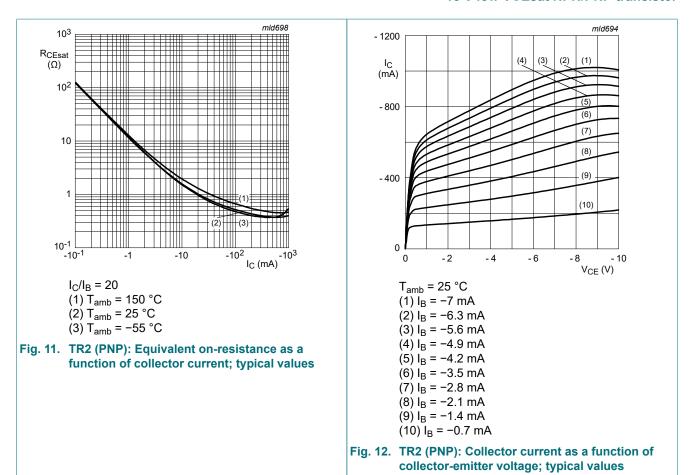
(2)
$$T_{amb} = 25 \, ^{\circ}C$$

(3)
$$T_{amb} = -55 \, ^{\circ}C$$

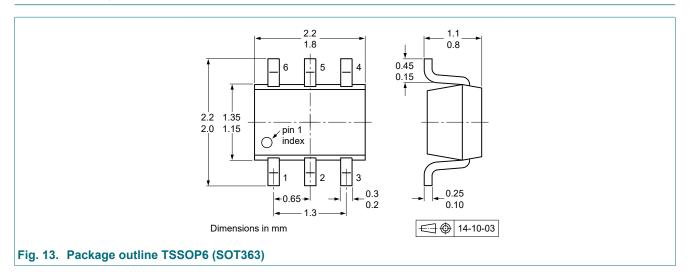
Fig. 10. TR2 (PNP): Base-emitter saturation voltage as a function of collector current; typical values

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15 V low VCEsat NPN/PNP transistor

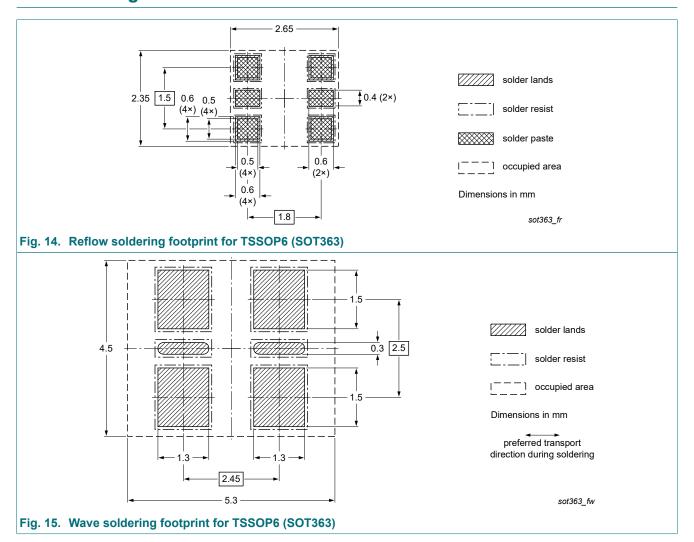


11. Package outline



15 V low VCEsat NPN/PNP transistor

12. Soldering



15 V low VCEsat NPN/PNP transistor

13. Revision history

Table 8. Revision history

Data sheet ID	Release date	Data sheet status	Change notice	Supersedes
PBSS2515YPN v.3	20221001	Product data sheet	-	PBSS2515YPN v.2
Modifications:	Nexperia. • Legal texts have	this data sheet has been rede we been adapted to the new onged to non-automotive qual ().	company name where	appropriate.
PBSS2515YPN v.2	20050111	Product data sheet	-	PBSS2515YPN v.1
PBSS2515YPN v.1	20020508	Product data sheet	-	-

15 V low VCEsat NPN/PNP transistor

14. Legal information

Data sheet status

Document status [1][2]	Product status [3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

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